Designer's™ Data Sheet

Insulated Gate Bipolar Transistor

N-Channel Enhancement-Mode Silicon Gate

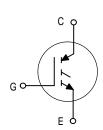
This Insulated Gate Bipolar Transistor (IGBT) uses an advanced termination scheme to provide an enhanced and reliable high voltage–blocking capability. Short circuit rated IGBT's are specifically suited for applications requiring a guaranteed short circuit withstand time such as Motor Control Drives. Fast switching characteristics result in efficient operations at high frequencies.

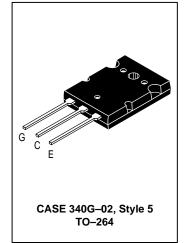
- Industry Standard High Power TO-264 Package (TO-3PBL)
- High Speed E_{off}: 60 μJ per Amp typical at 125°C
- High Short Circuit Capability 10 μs minimum
- Robust High Voltage Termination
- Robust RBSOA



Motorola Preferred Device

IGBT IN TO-264 40 A @ 90°C 66 A @ 25°C 600 VOLTS SHORT CIRCUIT RATED





MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit	
Collector–Emitter Voltage	VCES	600	Vdc	
Collector–Gate Voltage (R _{GE} = 1.0 MΩ)	VCGR	600	Vdc	
Gate–Emitter Voltage — Continuous	VGE	±20	Vdc	
Collector Current — Continuous @ T _C = 25°C — Continuous @ T _C = 90°C — Repetitive Pulsed Current (1)	IC25 IC90 ICM	66 40 132	Adc Apk	
Total Power Dissipation @ T _C = 25°C Derate above 25°C	PD	260 2.08	Watts W/°C	
Operating and Storage Junction Temperature Range	TJ, T _{stg}	-55 to 150	°C	
Short Circuit Withstand Time (V _{CC} = 360 Vdc, V _{GE} = 15 Vdc, T _J = 25°C, R _G = 20 Ω)	t _{SC}	10	μs	
Thermal Resistance — Junction to Case – IGBT — Junction to Ambient	R _θ JC R _θ JA	0.48 35	°C/W	
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 seconds	TL	260	°C	
Mounting Torque, 6–32 or M3 screw	10 lbf•in (1.13 N•m)			

⁽¹⁾ Pulse width is limited by maximum junction temperature.

Designer's Data for "Worst Case" Conditions — The Designer's Data Sheet permits the design of most circuits entirely from the information presented. SOA Limit curves — representing boundaries on device characteristics — are given to facilitate "worst case" design.

Preferred devices are Motorola recommended choices for future use and best overall value.



MGY40N60

Cha	racteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector–to–Emitter Breakdown Vo (V _{GE} = 0 Vdc, I _C = 250 μAdc) Temperature Coefficient (Positive		BVCES	600 —	— 870	_	Vdc mV/°C
Emitter-to-Collector Breakdown Voltage (V _{GE} = 0 Vdc, I _{EC} = 100 mAdc)		BVECS	25	_	_	Vdc
Zero Gate Voltage Collector Currer (VCE = 600 Vdc, VGE = 0 Vdc) (VCE = 600 Vdc, VGE = 0 Vdc, T		ICES	=	_	100 2500	μAdc
Gate-Body Leakage Current (VGE = ± 20 Vdc, VCE = 0 Vdc)		IGES	_	_	250	nAdc
ON CHARACTERISTICS (1)		•	•	•		•
Collector-to-Emitter On-State Volt (VGE = 15 Vdc, I _C = 20 Adc) (V _{GE} = 15 Vdc, I _C = 20 Adc, T _J (V _{GE} = 15 Vdc, I _C = 40 Adc)		VCE(on)		2.20 2.10 2.60	2.80 — 3.25	Vdc
Gate Threshold Voltage (V _{CE} = V _{GE} , I _C = 1 mAdc) Threshold Temperature Coefficie	nt (Negative)	VGE(th)	4.0 —	6.0 10	8.0 —	Vdc mV/°C
Forward Transconductance (V _{CE} =	= 10 Vdc, I _C = 40 Adc)	9fe	_	12	_	Mhos
DYNAMIC CHARACTERISTICS						
Input Capacitance	(V _{CE} = 25 Vdc, V _{GE} = 0 Vdc, f = 1.0 MHz)	C _{ies}	_	6810	_	pF
Output Capacitance		C _{oes}	_	464	_	
Transfer Capacitance	,	C _{res}	_	15	_	
SWITCHING CHARACTERISTICS (1)					
Turn-On Delay Time		^t d(on)	_	126	_	ns
Rise Time	$(V_{CC} = 360 \text{ Vdc}, I_{C} = 40 \text{ Adc},$	t _r	_	95	_	
Turn-Off Delay Time	V _{GE} = 15 Vdc, L = 300 μH R _G = 20 Ω, T _J = 25°C) Energy losses include "tail"	td(off)	_	530	_	1
Fall Time		t _f	_	180	_]
Turn-Off Switching Loss		E _{off}	_	1.50	2.10	mJ
Turn-On Delay Time	$(V_{CC}=360~Vdc,~I_{C}=40~Adc,~V_{GE}=15~Vdc,~L=300~\mu H~R_{G}=20~\Omega,~T_{J}=125^{\circ}C)$ Energy losses include "tail"	^t d(on)	_	113	_	ns
Rise Time		t _r	_	104	_	1
Turn-Off Delay Time		t _d (off)	_	588	_	1
Fall Time		t _f	_	346	_	1
Turn-Off Switching Loss		E _{off}	_	2.70	_	mJ
Gate Charge		QT	_	248	_	nC
	$(V_{CC} = 360 \text{ Vdc}, I_{C} = 40 \text{ Adc}, V_{GE} = 15 \text{ Vdc})$	Q ₁	_	49	_	1
		Q ₂	_	81	_	1
INTERNAL PACKAGE INDUCTANO	E	•	•	•		•
Internal Emitter Inductance (Measured from the emitter lead 0.25" from package to emitter bond pad)		LE	_	13	_	nH

⁽¹⁾ Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

TYPICAL ELECTRICAL CHARACTERISTICS

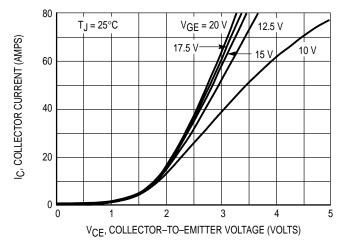
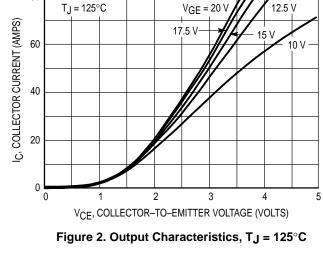


Figure 1. Output Characteristics, T_J = 25°C



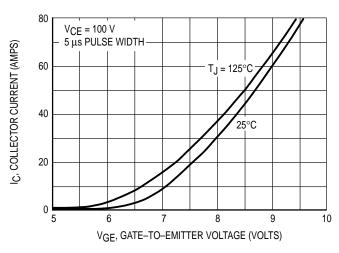


Figure 3. Transfer Characteristics

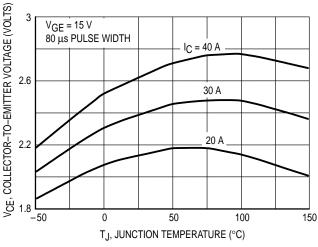


Figure 4. Collector-to-Emitter Saturation Voltage versus Junction Temperature

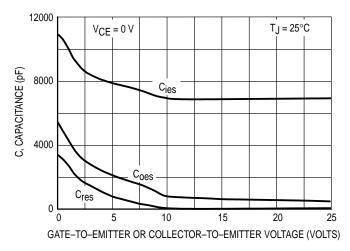


Figure 5. Capacitance Variation

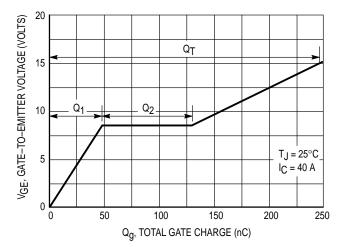


Figure 6. Gate-to-Emitter Voltage versus
Total Charge

MGY40N60

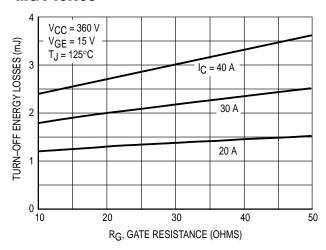


Figure 7. Turn–Off Losses versus
Gate Resistance

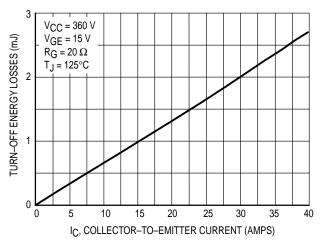


Figure 9. Turn-Off Losses versus Collector-to-Emitter Current

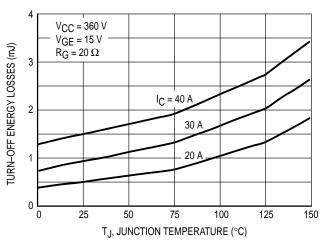


Figure 8. Turn-Off Losses versus Junction Temperature

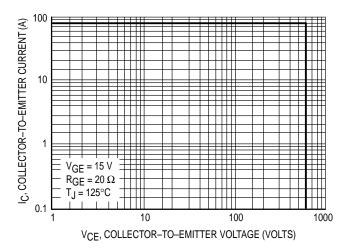
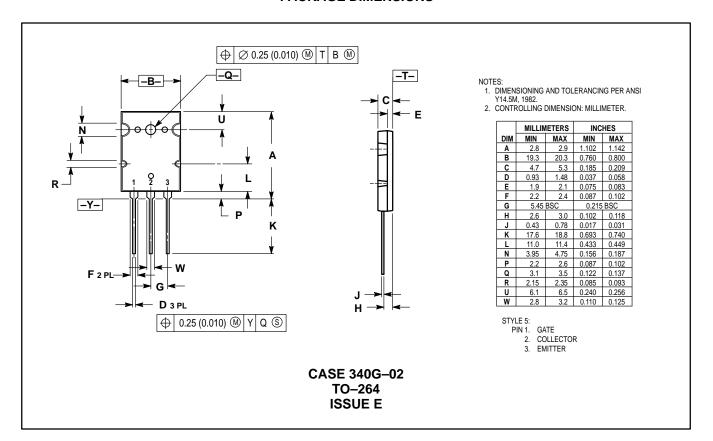


Figure 10. Reverse Biased Safe Operating Area

PACKAGE DIMENSIONS



MGY40N60

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Motorola data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

How to reach us:

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 20912; Phoenix, Arizona 85036. 1–800–441–2447 or 602–303–5454

MFAX: RMFAX0@email.sps.mot.com – TOUCHTONE 602–244–6609 INTERNET: http://Design-NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi–SPD–JLDC, 6F Seibu–Butsuryu–Center, 3–14–2 Tatsumi Koto–Ku, Tokyo 135, Japan. 03–81–3521–8315

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298



MGY40N60/D